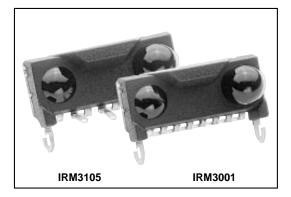
SIEMENS





FEATURES

- Compatible with IrDA Specifications
- Wide Dynamic Range
- Automatic Threshold Control
- Shutdown Feature Reduces Quiescent Current In Standby Mode
- Surface Mounted Package, Ideal For Automated Assembly

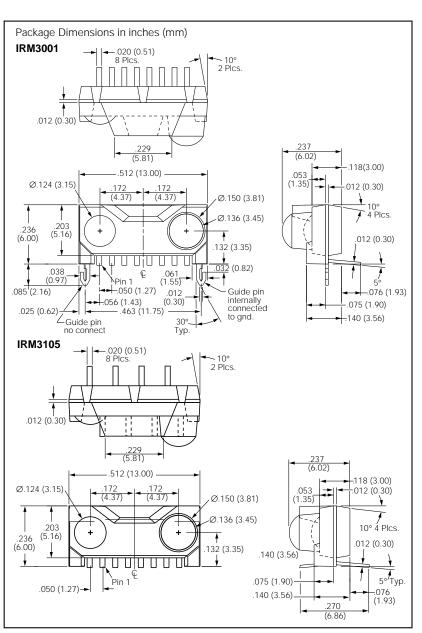
APPLICATIONS

- Wireless Computer and Peripheral Communications
- Wireless Computer and Telephone
 Communications
- Interactive TV and Remote Control

DESCRIPTION

The IRM 3001/3105 is an integrated Infrared transceiver that is compatible with the IrDA Serial Infrared (SIR) Physical Layer Link Specification. Housed in a single molded epoxy surface mount package this unique product lends itself easily to automated pick and place assembly.

State of the art BiCMOS circuitry coupled with Siemens optoelectronic expertise makes for a product that outperforms its closest rival. Siemens unique circuit configuration automatically compensates for the wide range of potential illumination prevalent in the usage of the transceiver as the distance between the communicating devices changes over the allowable range. Also incorporated in the module is a unique shutdown feature which allows for a power down mode. This will greatly aid in lowering the quiescent current when the module is not being used. In normal operation the shutdown pin sould be held low.

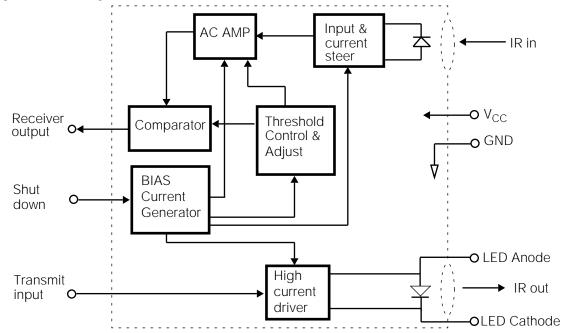


IRM3001 Pin Functions

Pin no.	Function	Pin no.	Function	Pin no.	Function
1	LED Anode	4	Receive	7	NC
2	LED Cathode	5	Shut down	8	GND
3	Transmit	6	V _{CC}		

IRM3105 Pin Functions

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1	LED Cathode	4	GND	7	Transmit
2	Receive	5	NC	8	LED Anode
3	V _{CC}	6	Shut down		



Parameter	Test Condition	Symbol	Value	Unit
Supply voltage range		V _{CC}	-0.5 to +6	V
Input currents	All pins		10	mA
Output sinking current			25	mA
Storage temperature		Τ _S	-25 to +85	°C
Ambient temperature	Operating	T _A	0 to 70	°C
Junction temperature	Maximum	ΤJ	125	°C
Power dissipation		P _{tot}	200	mW
Average IR LED current	DC	I _{LED}	100	mA
Rep pulsed IR LED current	<90 µs, t _{on} , <20%	I _{LED (RP)}	500	mA
Peak IR LED current	<2 µs, t _{on} , <10%	I _{LED (PK)}	1.0	А
IR LED anode voltage		V _{LEDA}	–0.5 to V _{CC} +0.5 V	V
IR LED cathode voltage		V _{LEDK}	–0.5 to V _{CC} +0.5 V	V
Transmit data input voltage		V _{TXD}	-0.5 to V _{CC} +0.5 V	V
Receive data output voltage		V _{RXD}	-0.5 to V _{CC} +0.5 V	V

Absolute Maximum Ratings (at 25°C)

IR Convection Reflow Soldering

As with all optoelectronic devices, the IRM3001/3105 is sensitive to temperature rates of change and peak temperatures during the solder process. It is not designed for any application in which the component would be directly immersed in molten solder. Optimum performance will be achieved with convection IR reflow soldering.

A preheat of up to 120°C for 2.5 minutes is recommended with a rampup to soldering heat of a maximum of 4°C/sec.

The maximum peak temperature is 240°C and should not exceed 10 seconds at that temperature.

Cool down rate should not exceed 3°C/sec.

Basic Module Parameters

Parameter	Test Condition	Symbol	Min.	Тур.	Max.	Unit
Supported data rates		D _{TR}	2.4		115.2	Kbit/s
Supply voltage range		V _{CC}	4.5	5	5.5	V
Supply current receive	SD=low or NC Receive mode	I _{SR}		1		mA
Supply current	SD high, standby mode	I _{SSB}			0.25	mA

Receive Parameters

Parameter	Test Condition	Symbol	Min.	Тур.	Max.	Unit
Output voltage low	I _{OL} =4 mA	V _{OL}		0.5	0.8	V
Output voltage high	I _{OH} =-2 mA	V _{OH}	V _{CC} - .5			V
Output current					4	mA
Logic high input irradiance	Bit error rate=10 ⁻⁸	E _{IHmin}	4			µW/cm ²
Logic high input irradiance	In band irradiance maximum	E _{IHmax}			500	mW/cm ²
Maximum DC irradiance	Ambient interference DC	E _{ADC}	490			μW/cm ²
Minimum detection threshold irra- diance		E _{Emin}		3.0		μW/cm ²
Logic low input irradiance	Ambient interference pulsed	E _{IL}			0.4	µW/cm ²
Rise time, fall time	C=15 pf	t _r , t _f	20		200	ns
Output pulse width	115.2 Kbits/sec.		1	1.6	6	μs
Output delay leading edge	Output level=0.5 x V _{CC} , E_{IH} =4 μ W/cm ²				2	μs
Contributed systematic jitter		CSJ			0.2	μs
Output delay trailing edge	Output level=0.5 x V _{CC} , E_{IH} =4 μ W/cm ²			1	5	μs
Latency	Recovery of last transmitted pulse to 1.1 x threshold sensitivity	IL		100	600	μs

Transmit Parameters

Parameter	Test Condition	Symbol	Min.	Тур.	Max.	Unit
Driver current IR LED	5 V ⁽¹⁾	I _{LED}	250	350	500	mA
Logic low input voltage		V _{IL}	0		0.3	V
Logic high input voltage		V _{IH}	2.5		V _{CC}	V
Output radiant intensity	5 V, α=15°	RI	40	60	500	mW/Sr
Half angle		а		22		Deg.
Peak wavelength, emission		λ _P		880		nm
Spectral bandwidth	I _F =100 mA	ΔΙ		80		nm
Optical rise/fall time	10% to 90%, 90% to 10%	t _r , t _f		200	600	ns
Optical overshoot					25	%
Contributed systematic jitter					0.2	μs

Notes:

1. Internal current regulation. Do not use a current limiting resistor.

2. For proper operation, the LED anode should be connected to $V_{\mbox{CC}}.$